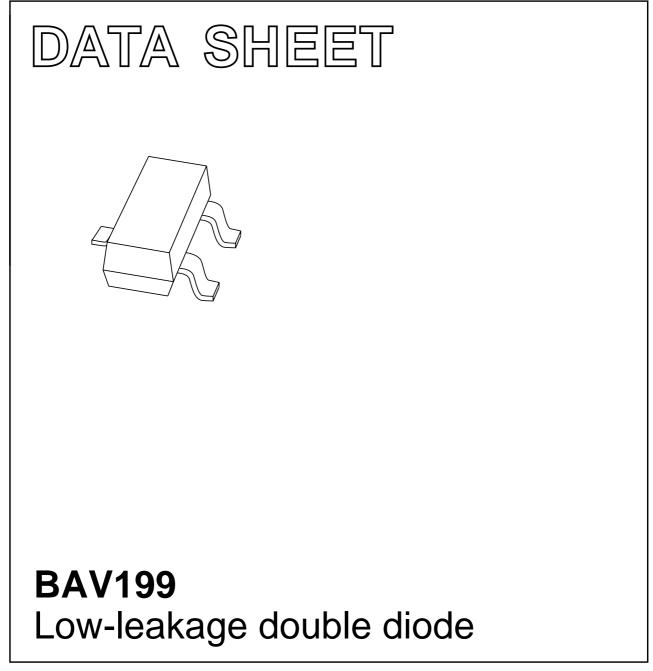
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 May 11 2001 Oct 12



MARKING

Note

TYPE NUMBER

BAV199

1. * = p: Made in Hong Kong.

* = t: Made in Malaysia.

* = W: Made in China.

FEATURES

- Plastic SMD package
- Low leakage current: typ. 3 pA
- Switching time: typ. 0.8 μs
- · Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA.

APPLICATION

· Low-leakage current applications in surface mounted circuits.

DESCRIPTION

Epitaxial, medium-speed switching, double diode in a small SOT23 plastic SMD package. The diodes are connected in series.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V _{RRM}	repetitive peak reverse voltage		-	85	V
V _R	continuous reverse voltage		-	75	V
I _F	continuous forward current	single diode loaded; note 1; see Fig.2	-	160	mA
		double diode loaded; note 1; see Fig.2	-	140	mA
I _{FRM}	repetitive peak forward current		-	500	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		$t_p = 1 \ \mu s$	-	4	А
		t _p = 1 ms	-	1	А
		$t_p = 1 s$	-	0.5	А
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

Note

1. Device mounted on a FR4 printed-circuit board.

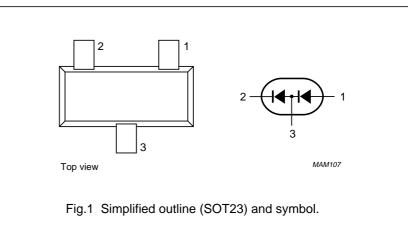
PINNING

MARKING

CODE⁽¹⁾

JY*

PIN	DESCRIPTION	
1	anode	
2	cathode	
3	anode; cathode	



PIN	DESCRIPTION			
1	anode			
2	cathode			
3	anode; cathode			

BAV199

BAV199

ELECTRICAL CHARACTERISTICS

 T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode	•		·	•	
V _F	forward voltage	see Fig.3			
		$I_F = 1 \text{ mA}$	-	900	mV
		I _F = 10 mA	-	1000	mV
		I _F = 50 mA	-	1100	mV
		I _F = 150 mA	-	1250	mV
I _R	reverse current	see Fig.5			
		V _R = 75 V	0.003	5	nA
		V _R = 75 V; T _j = 150 °C	3	80	nA
C _d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0; \text{ see Fig.6}$	2	-	pF
t _{rr}	reverse recovery time	when switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100$ Ω ;	0.8	3	μs
		measured at $I_R = 1$ mA; see Fig.7			

THERMAL CHARACTERISTICS

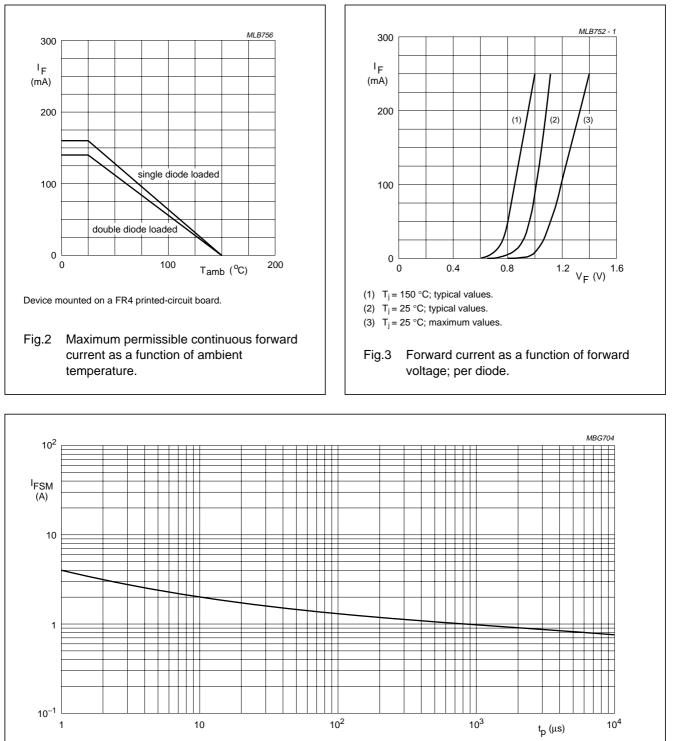
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		360	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Device mounted on a FR4 printed-circuit board.

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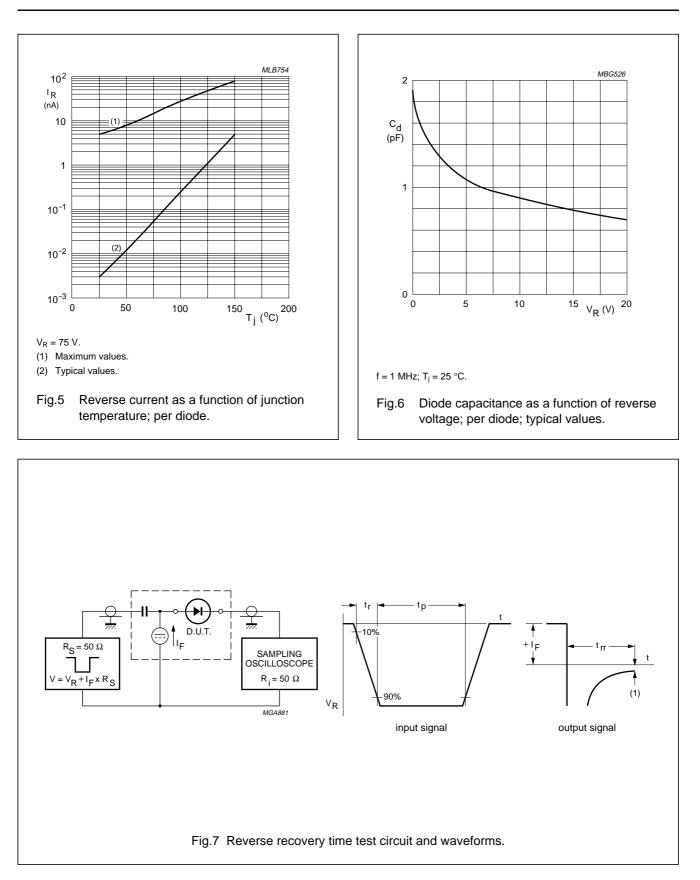
GRAPHICAL DATA

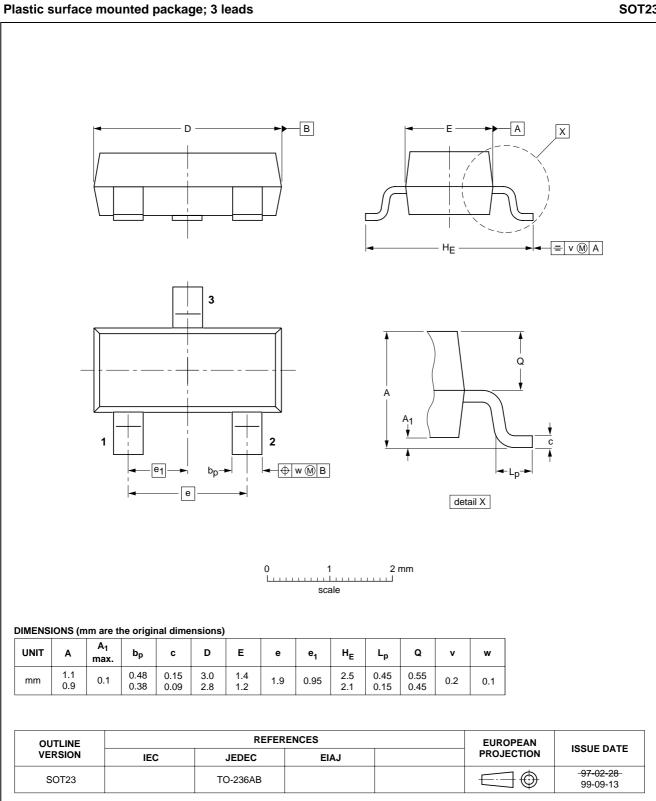


Based on square wave currents; $T_j = 25 \ ^\circ C$ prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration per diode.

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SOT23

BAV199

DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

Notes

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